

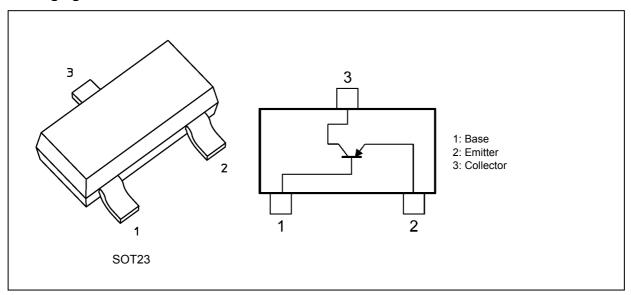
Bipolar Transistors Silicon PNP Epitaxial Type

# TBC857

#### 1. Applications

· Low-Frequency Amplifiers

#### 2. Packaging and Internal Circuit



### 3. Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		$V_{CBO}$	-50	V
Collector-emitter voltage		V <sub>CEO</sub>	-50	V
Emitter-base voltage		V <sub>EBO</sub>	-5	V
Collector current (DC)		Ic	-150	mA
Collector current (pulsed)		I <sub>CP</sub>	-200	
Base current		I <sub>B</sub>	-30	mA
Collector power dissipation	(Note 1)	P <sub>C</sub>	320	mW
Junction temperature		Tj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	℃

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device mounted on a 25.4 mm × 25.4 mm × 1.6 mm FR4 glass epoxy board (Cu pad: 0.42 mm<sup>2</sup> × 3)

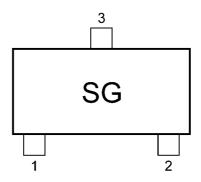


## 4. Electrical Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>		$V_{CB} = -30 \text{ V}, I_{E} = 0 \text{ mA}$	_	-1	-30	nA
Emitter cut-off current	I <sub>EBO</sub>		$V_{EB} = -5 \text{ V}, I_{C} = 0 \text{ mA}$	_	_	-0.1	μА
DC current gain	h <sub>FE</sub>	(Note 1)	$V_{CE} = -5 \text{ V}, I_{C} = -2 \text{ mA}$	210	_	475	_
Collector-emitter saturation	V <sub>CE(sat)</sub>		$I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$	_	-0.06	-0.3	V
voltage			I <sub>C</sub> = -100 mA, I <sub>B</sub> = -5 mA	_	-0.22	-0.65	
Base-emitter saturation voltage	V <sub>BE(sat)</sub>		$I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$	_	-0.7	_	V
			I <sub>C</sub> = -100 mA, I <sub>B</sub> = -5 mA	_	-0.85	_	
Base-emitter voltage	V <sub>BE</sub>		I <sub>C</sub> = -2 mA, V <sub>CE</sub> = -5 V	-0.6	-0.65	-0.75	V
			$I_C$ = -10 mA, $V_{CE}$ = -5 V	_	_	-0.82	
Transition frequency	f <sub>T</sub>		$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA},$ f = 100 MHz	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>		V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	_	4	_	pF
Noise figure	NF		$V_{CE}$ = -6 V, $I_{C}$ = -100 μA, f = 1 kHz, $R_{G}$ = 10 kΩ	_	1	10	dB

Note 1: hFE classification: B rank

## 5. Marking



#### 6. Characteristics Curves (Note)

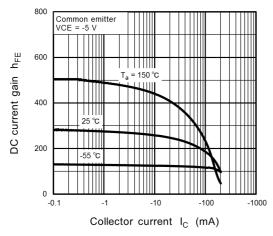


Fig. 6.1 hFE - IC

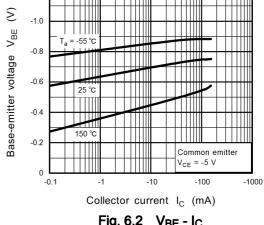


Fig. 6.2 V<sub>BE</sub> - I<sub>C</sub>

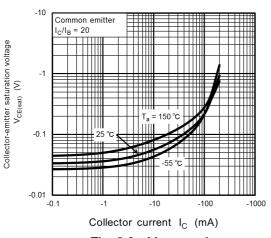
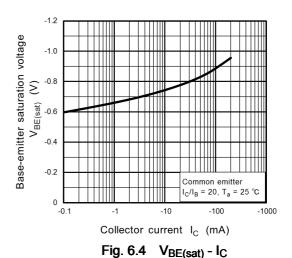


Fig. 6.3 V<sub>CE(sat)</sub> - I<sub>C</sub>



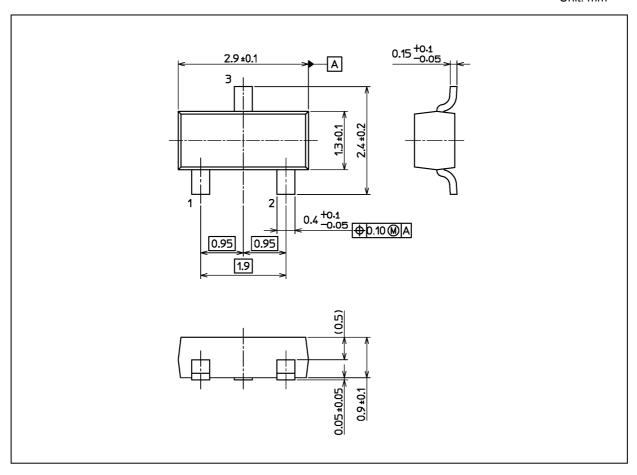
500  $P_{\rm C}$  (mW) Mounted on an FR4 board (25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm, Cu Pad: 0.42 mm<sup>2</sup>  $\times$  3) 400 Collector power dissipation 300 200 100 0 Ambient temperature  $T_a$  (°C) Fig. 6.5 P<sub>C</sub> - T<sub>a</sub>

The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 0.009 g (typ.)

Package Name(s)		
TOSHIBA: 2-3AB1A		
Nickname: SOT23		



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